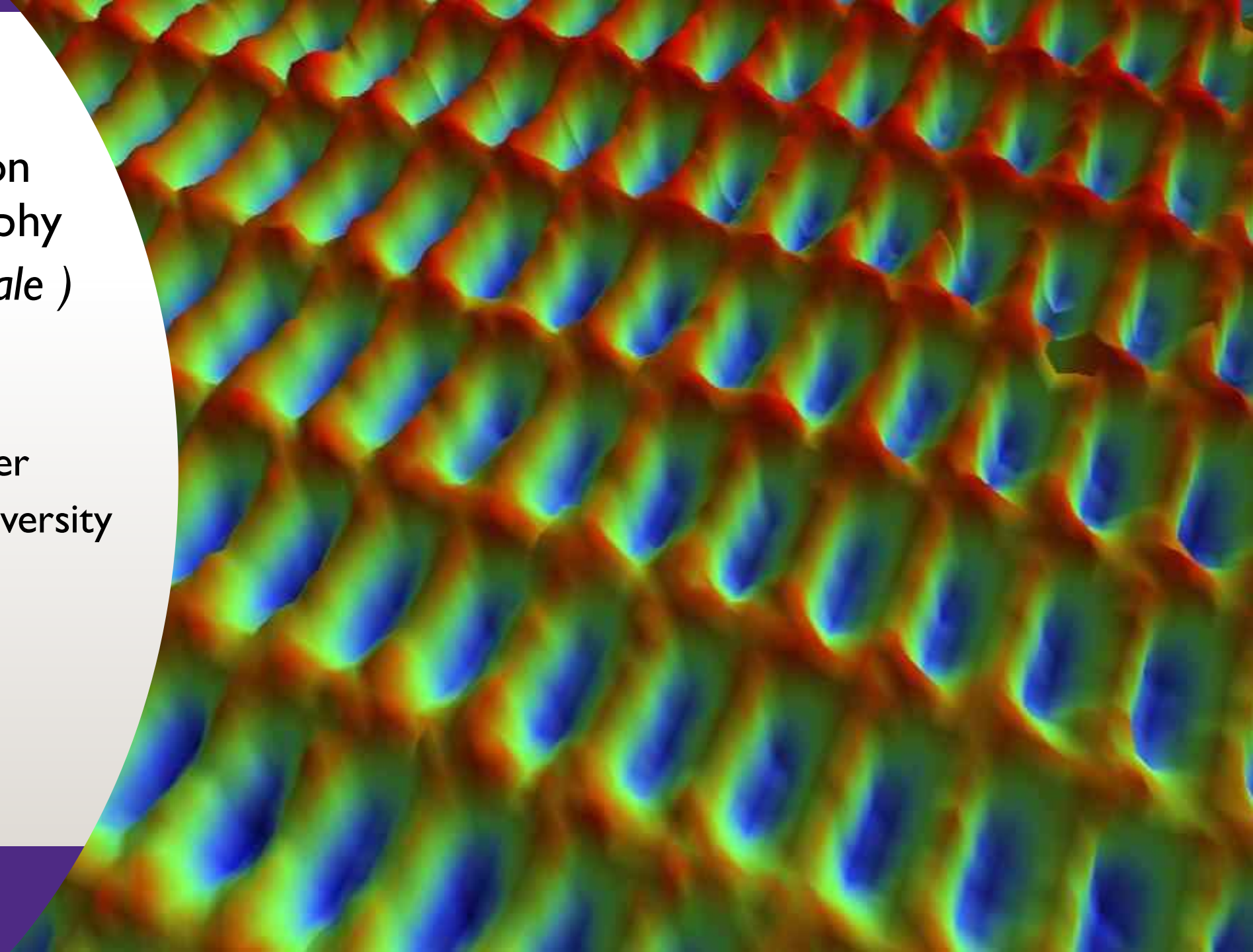


3D Characterization of Surface Topography (*From mm to nm scale*)

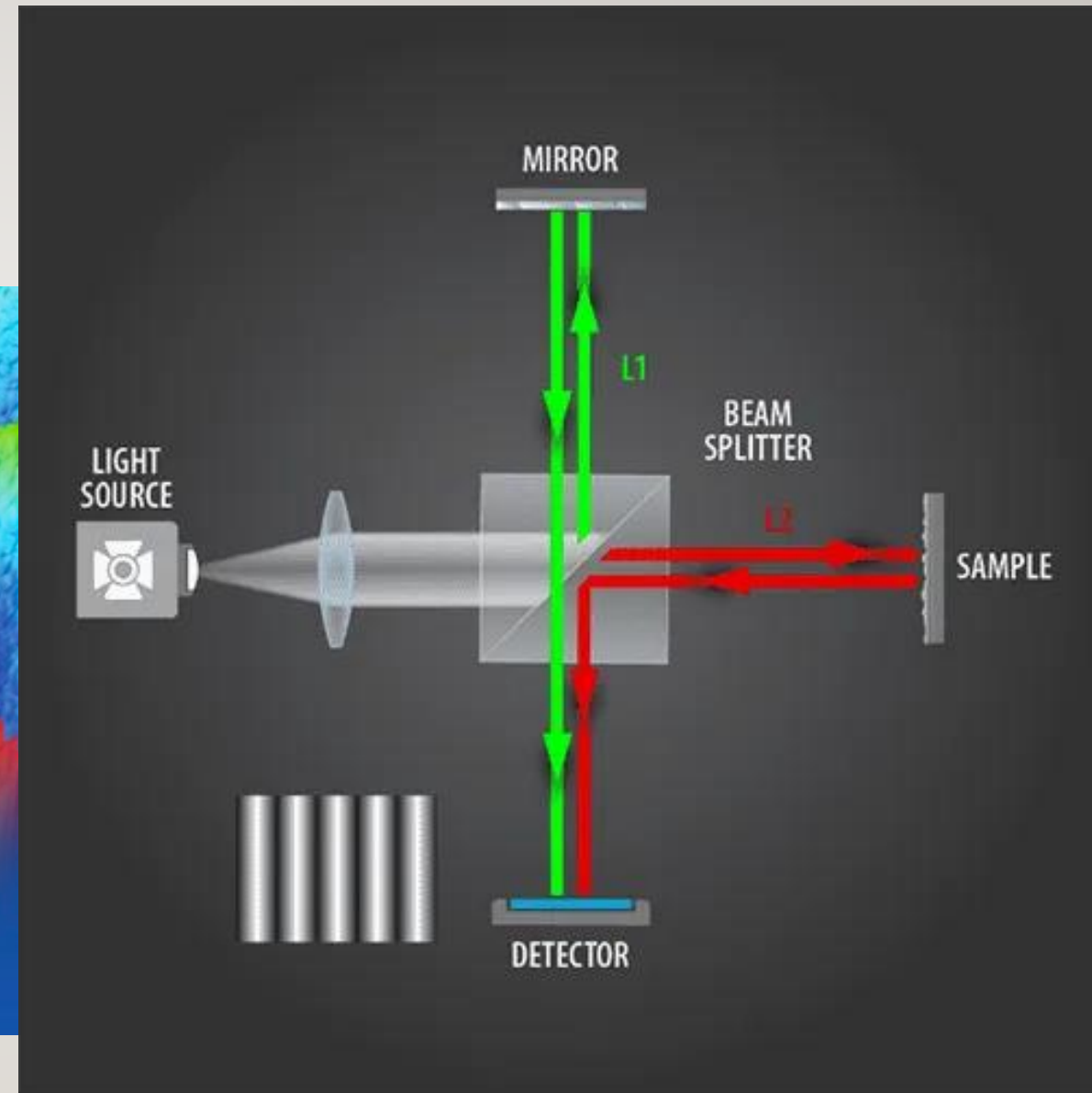
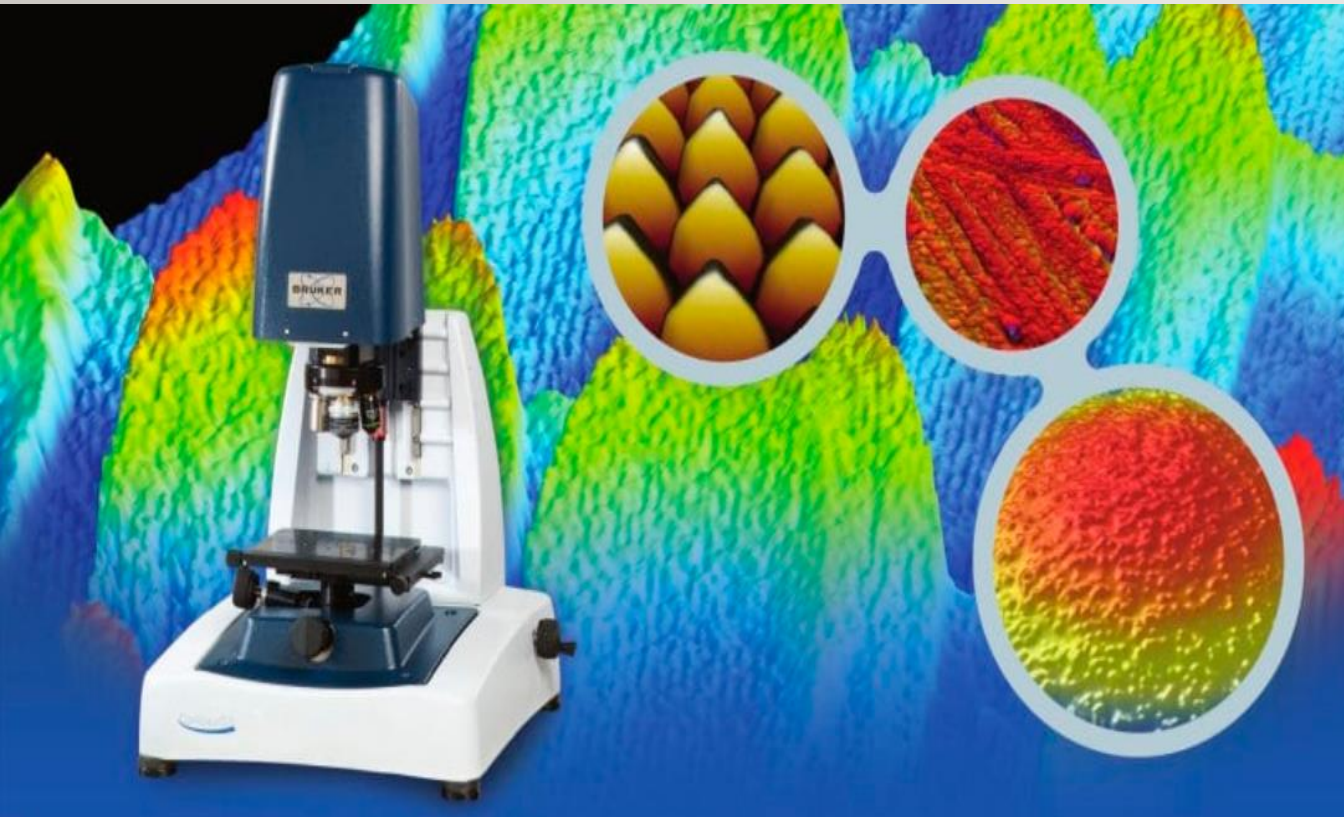
Xinqi Chen
Nuance Center
Northwestern University



- 3D Optical Microscope (Optical Profilometer, Non-contact Profilometer, White Light Interferometry – WLI)
- Stylus Profilometer (Contact Profilometer)
- Atomic Force Microscope (AFM) (Scanning Probe Microscope)
- The Comparison of the Strength and Weakness

SEM? No quantitative height information

Bruker Contour GT Optical Profilometer (3D Optical Microscope)

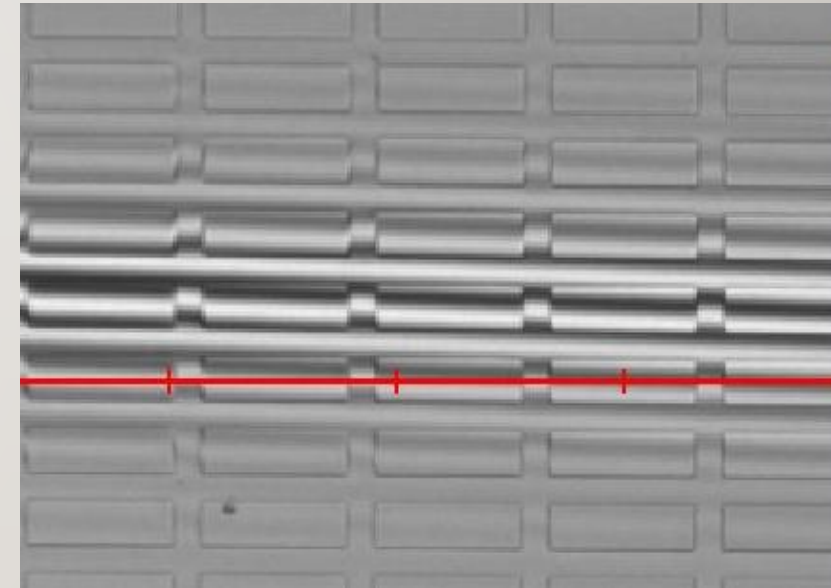


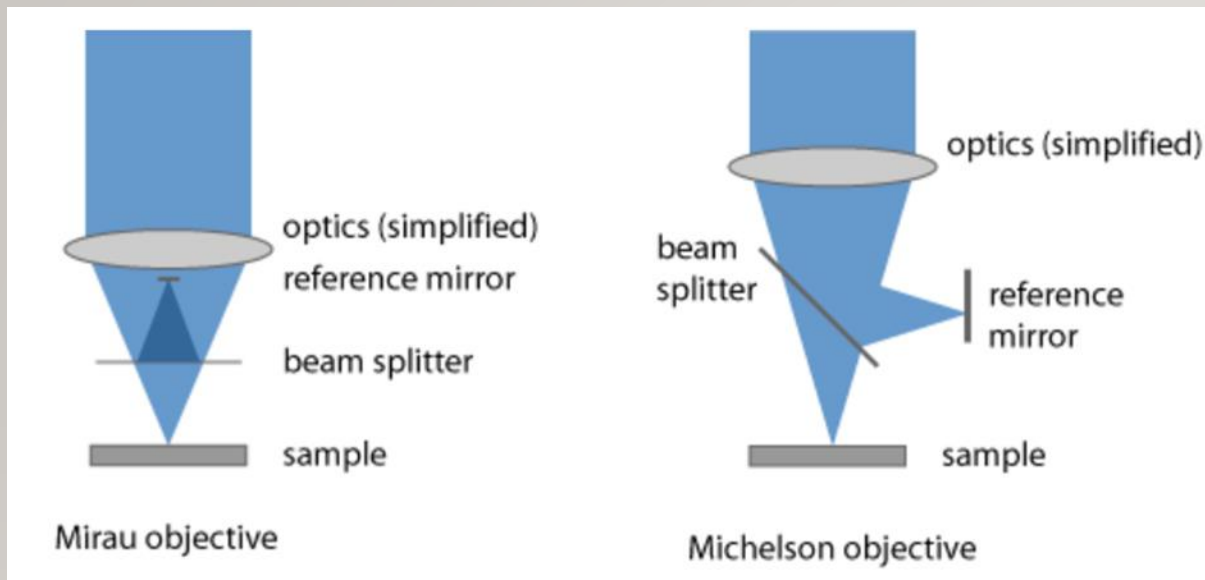
Working Principle of Profilometer (Non - Contact Optical Profilometer)

- A light beam is split, reflecting from reference (known/flat) & test material.
- Constructive and destructive interference occurs
- Forms the light and dark bands known as interference fringes.
- The optical path differences are due to height variances in the test surface.
- Constructive interference areas as lighter and the destructive interference areas as darker.
- Light to dark fringes above represents one-half a wavelength of difference between the reference path and the test path.

From the above Interference Image:

- Lower portion is out of focus means less interference.
- Greatest contrast means best focus.





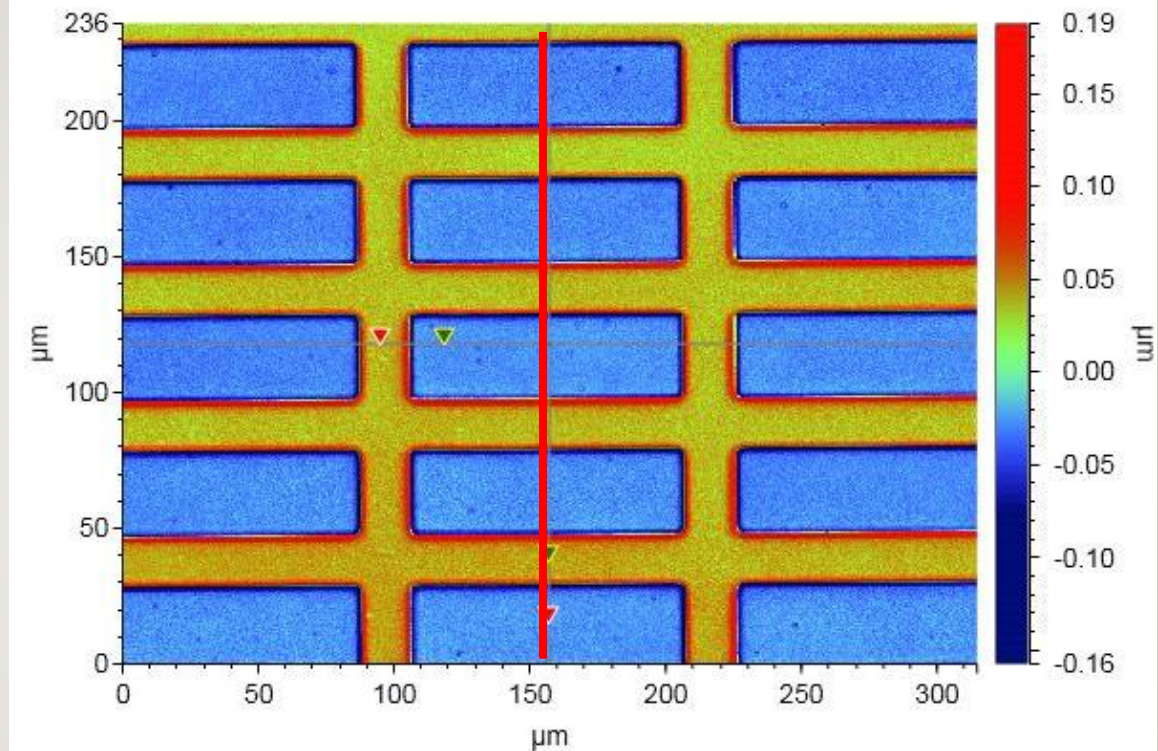
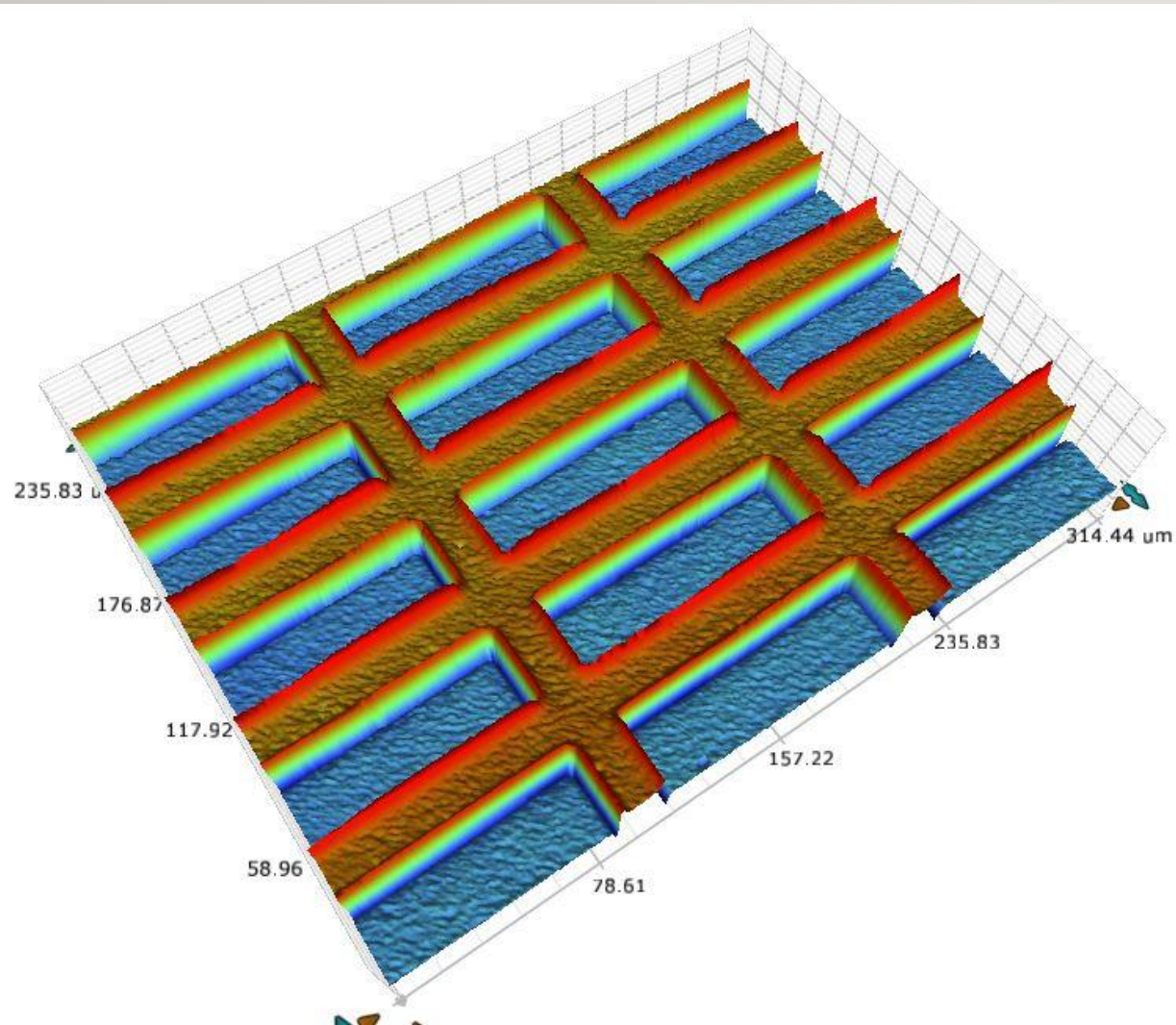
What does an optical profilometer measure?

Surface roughness
Step height

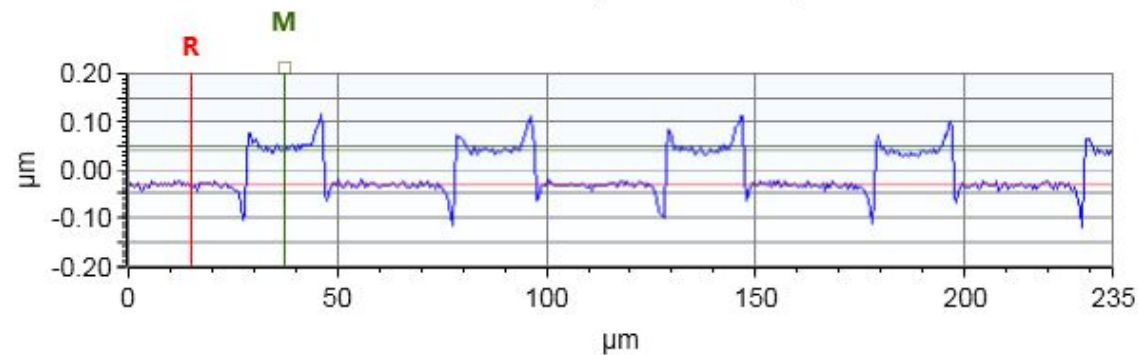
➤ INTERFEROMETRY MODE

- In PSI (Phase Shift Interferometry), a few z-shifts corresponding to known phase shifts are applied; they allow the surface to be reconstructed (smooth surfaces, samples with little roughness and steps < 120 nm).
- In VSI (Vertical Scanning Interferometry), a vertical scan is performed and the fringe envelope is observed to find the maximum correlation between the waves or focus point (samples with roughness ranging from 50 nm to 1 μm , step heights greater than 120 nm).

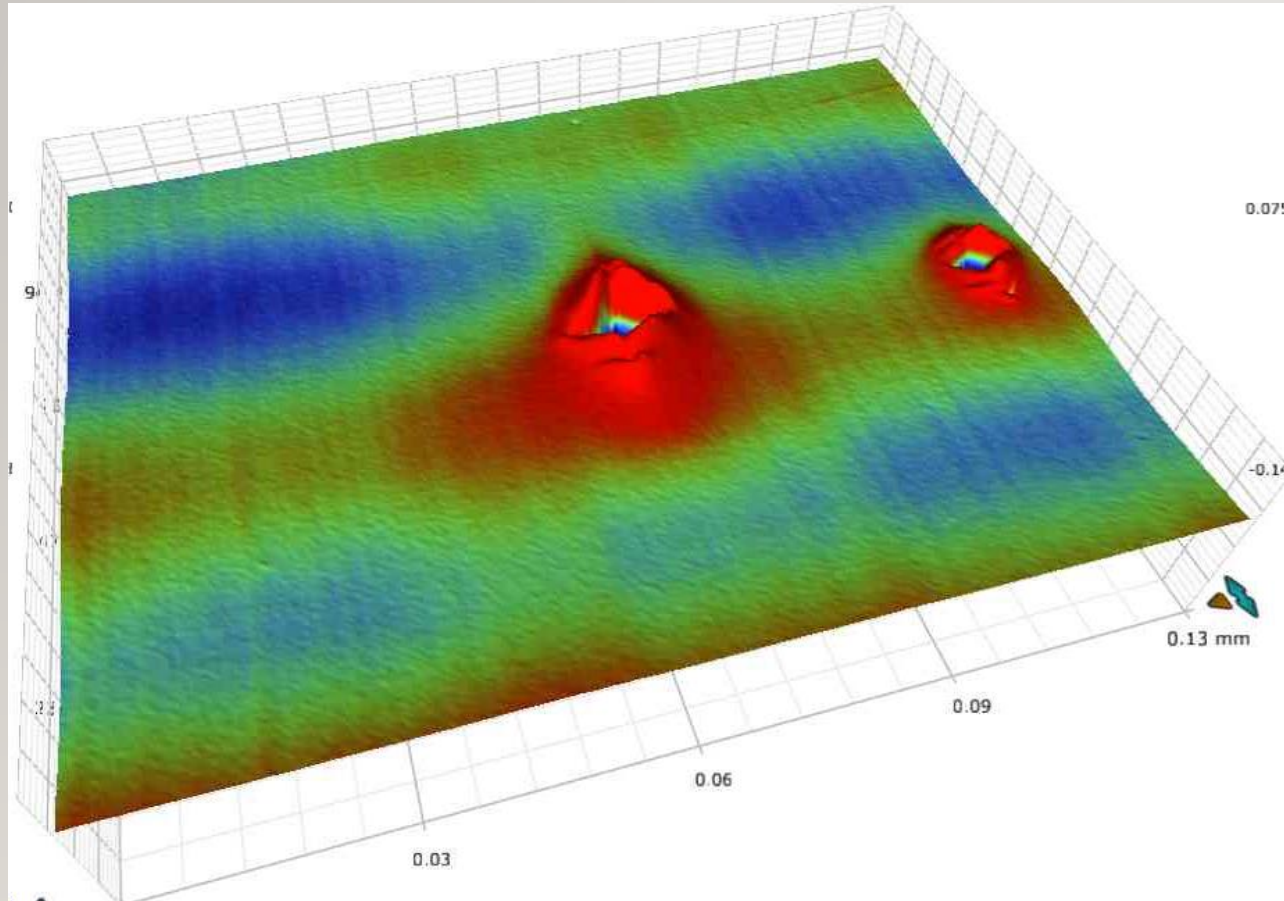
Silicon wafer with etched pattern



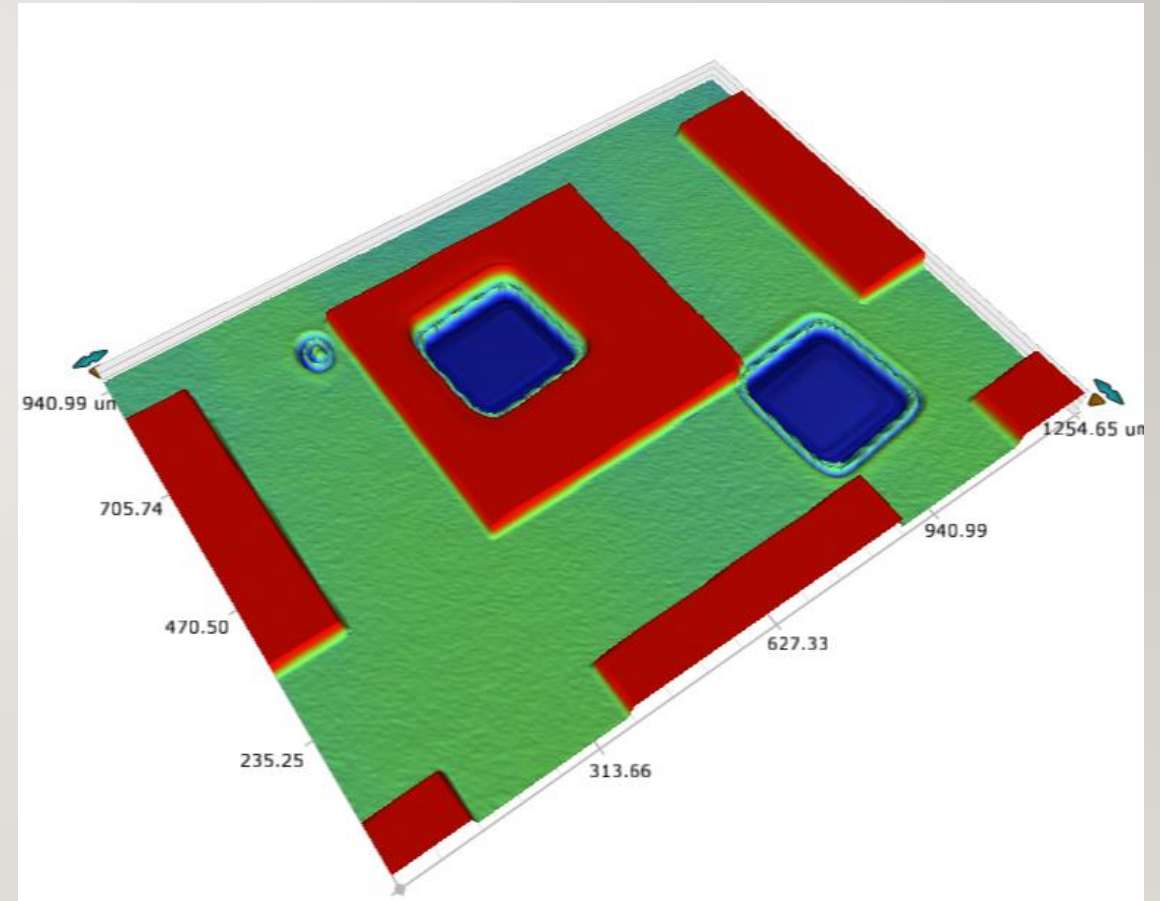
Y Profile: $\Delta X=22.2658 \mu\text{m}$; $\Delta Z=0.0731 \mu\text{m}$



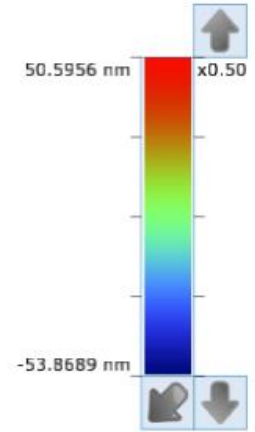
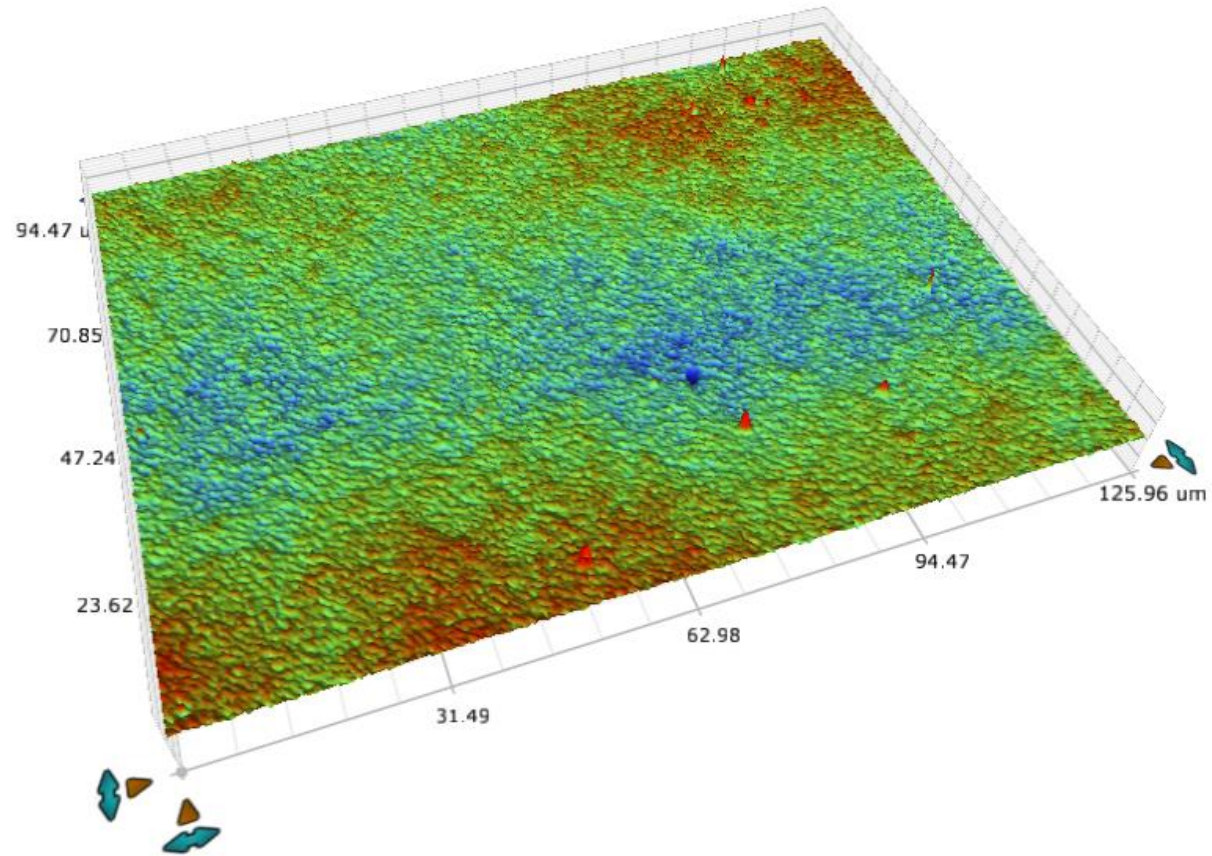
Crater made from nanoindentation



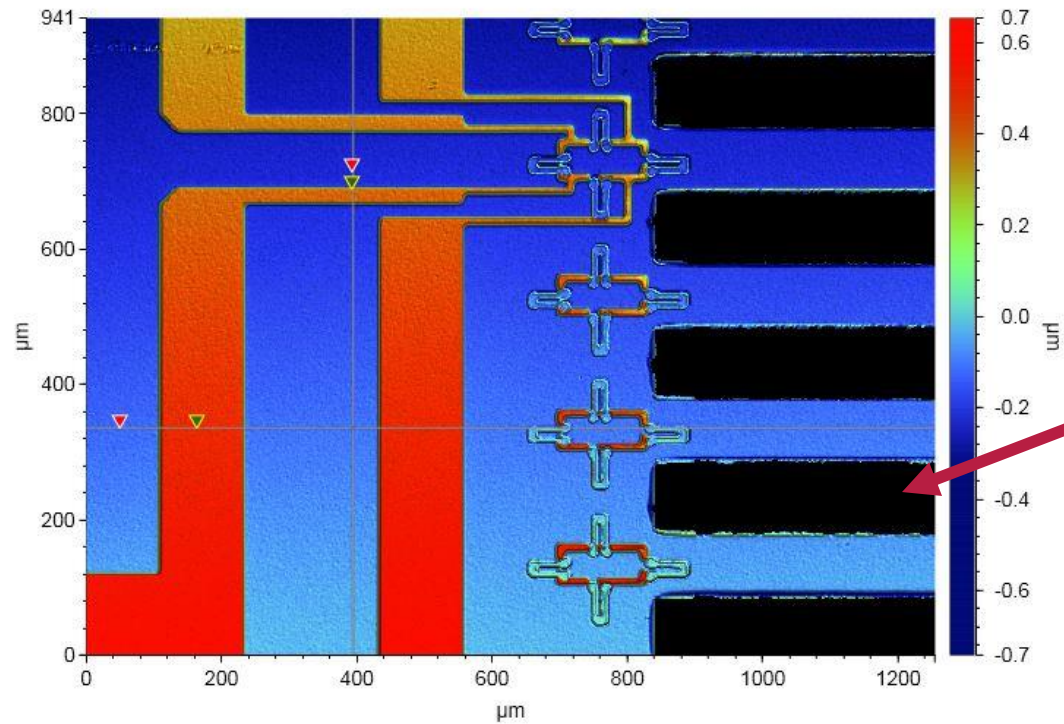
Crater made from SIMS depth profiling



Cu/Ti film on Si wafer

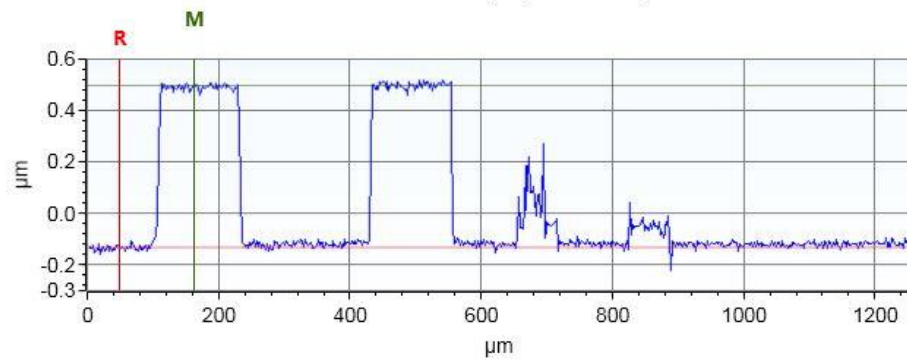


Analytical Results		
Label	Value	Units
Average	0	nm
Data Points	307200	
Percent Data Points	100	%
Ra	3.734	nm
Rp	50.6	nm
Rq	4.693	nm
Rt	0.1	μm
Rv	-53.87	nm

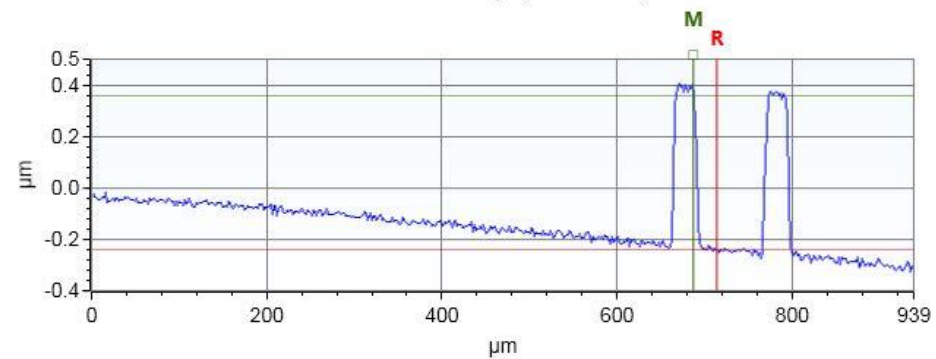


The wall is too sharp, and the bottom is too deep. No height information

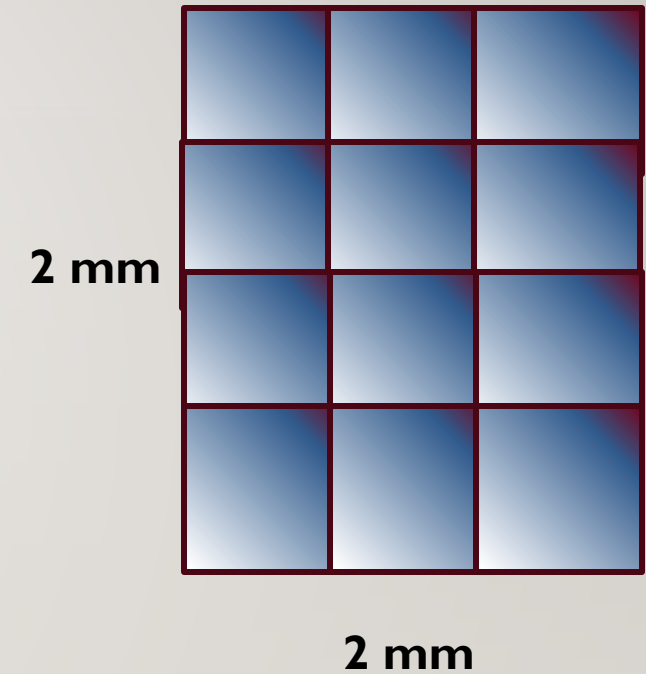
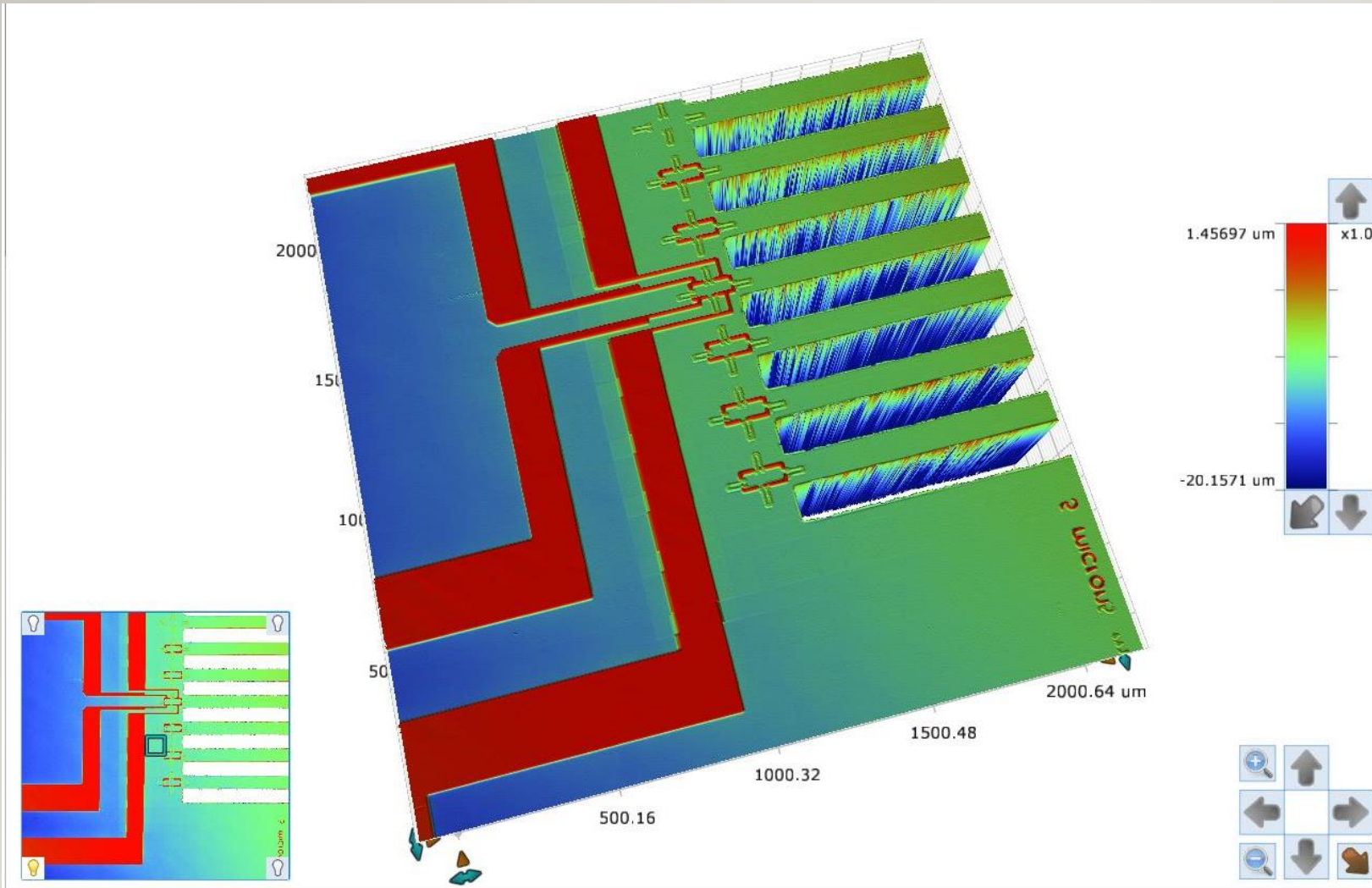
X Profile: $\Delta X=113.7030 \mu\text{m}$; $\Delta Z=0.6307 \mu\text{m}$



Y Profile: $\Delta X=-26.7939 \mu\text{m}$; $\Delta Z=0.5966 \mu\text{m}$



Stitching for mapping a big area



Optical Profilometer

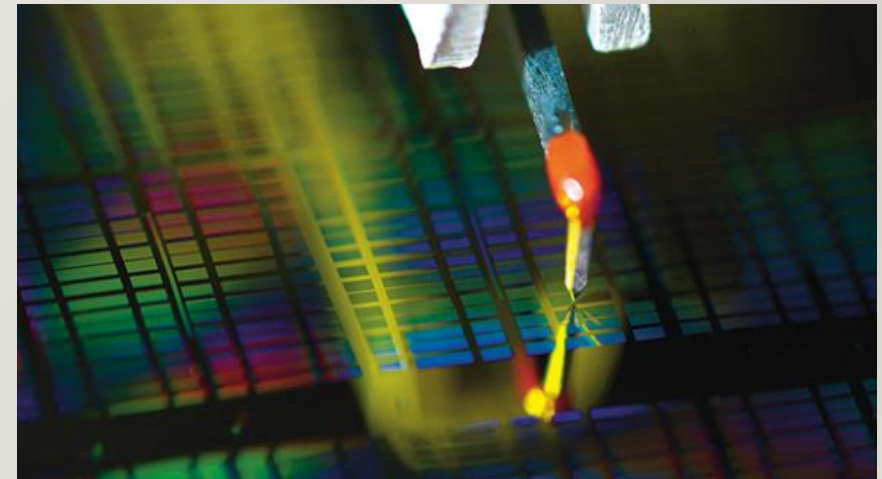
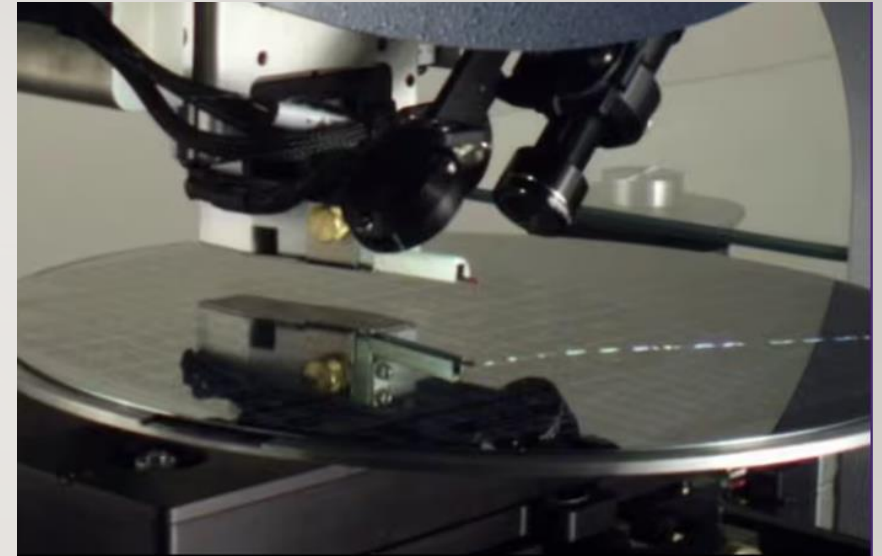
Advantages:

- Great vertical resolution in the nm level
- Lateral resolution ranges from a few micrometres down to 100 nm
- High Speed for 3D characterization
- No damage on surface wear or scratch
- Stitching capability to increase the maximum characterization size

Limitation:

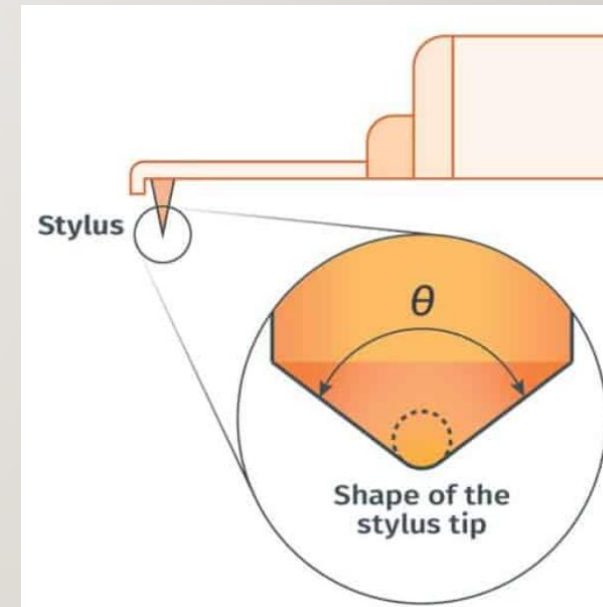
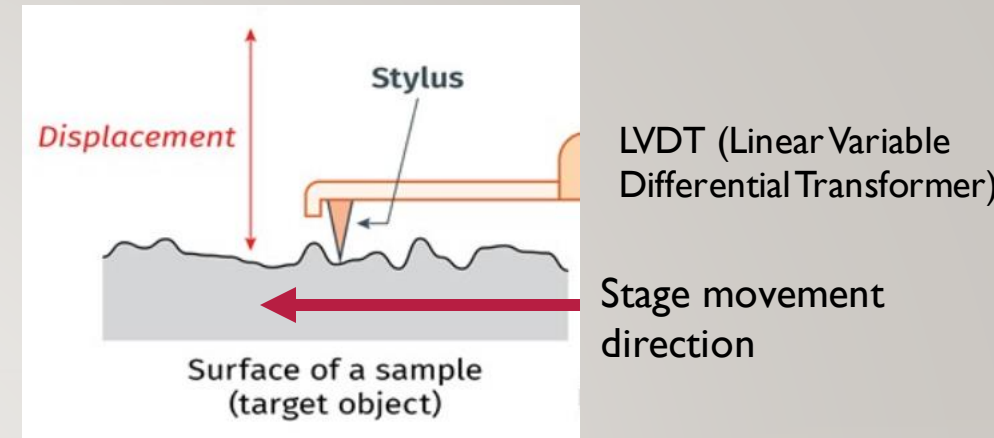
- Limited by very large slopes, where the light is reflected away from the objective, unless the slope has enough texture to provide the light.

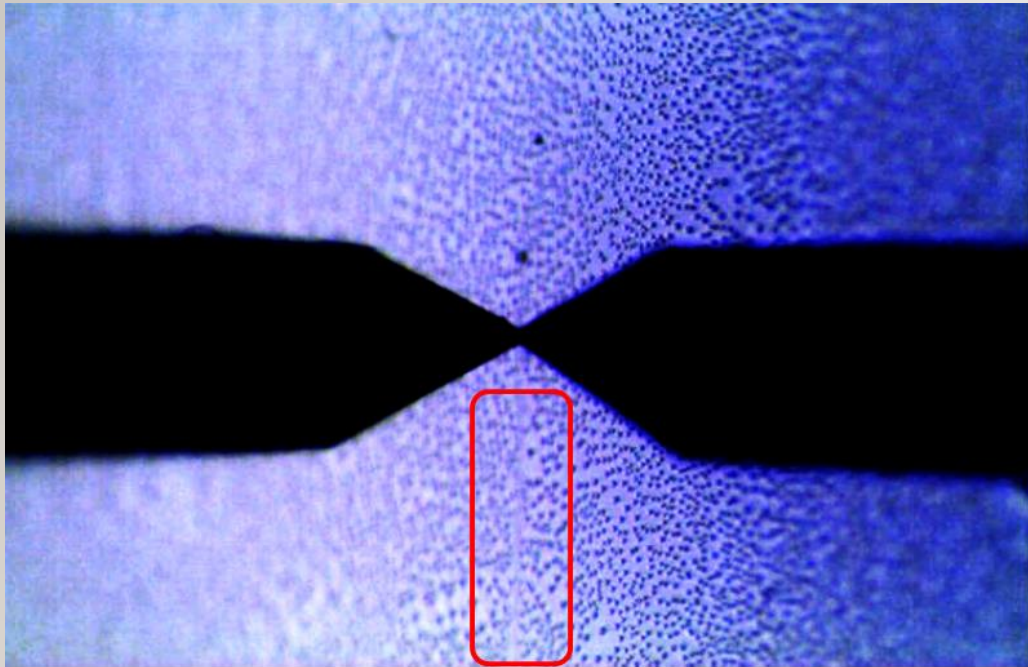
Stylus Profilometer



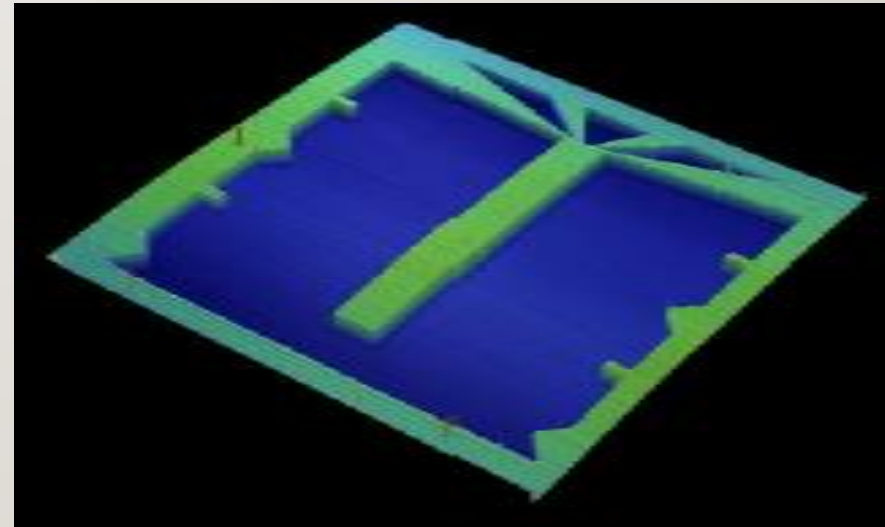
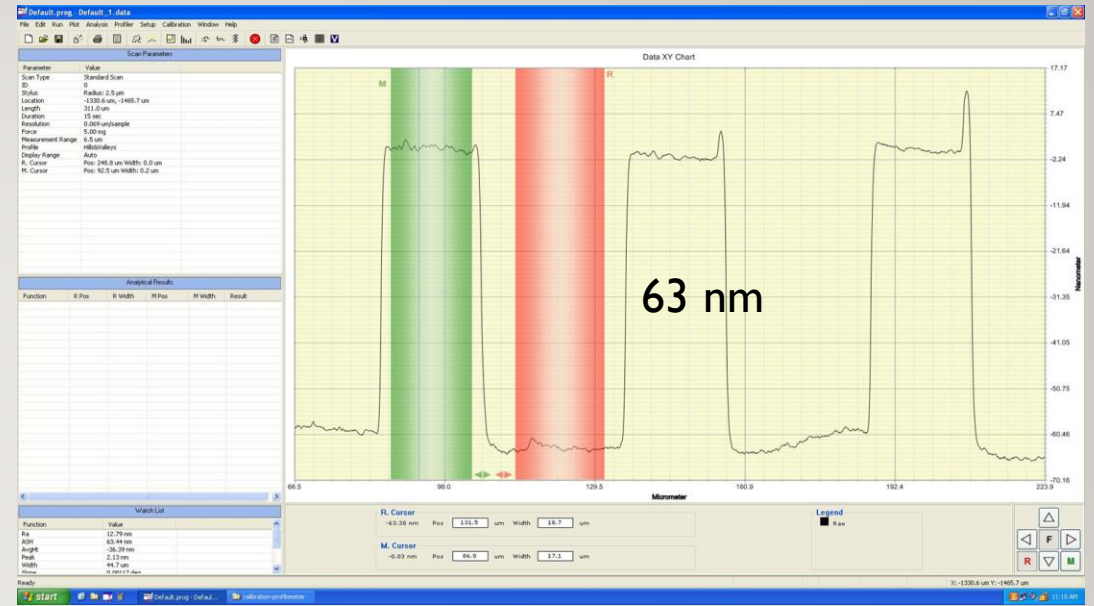
Stylus (contact) Profilometer

- The stylus profilometer provide repeatable, **reliable**, and accurate measurements- from traditional step height measurements and **2D roughness** surface characterization to advanced **3D mapping** and **film stress** analyses.
- A constant contact force is applied while the stylus moves laterally.
- The feedback controller lifts the stylus tip up or down to maintain constant force
- Tips are usually diamond. The tip radius dictates the lateral resolution.
- Tip radius ranges from 50 nm to 200 microns (**ours is 5 um**)





Surface scratch

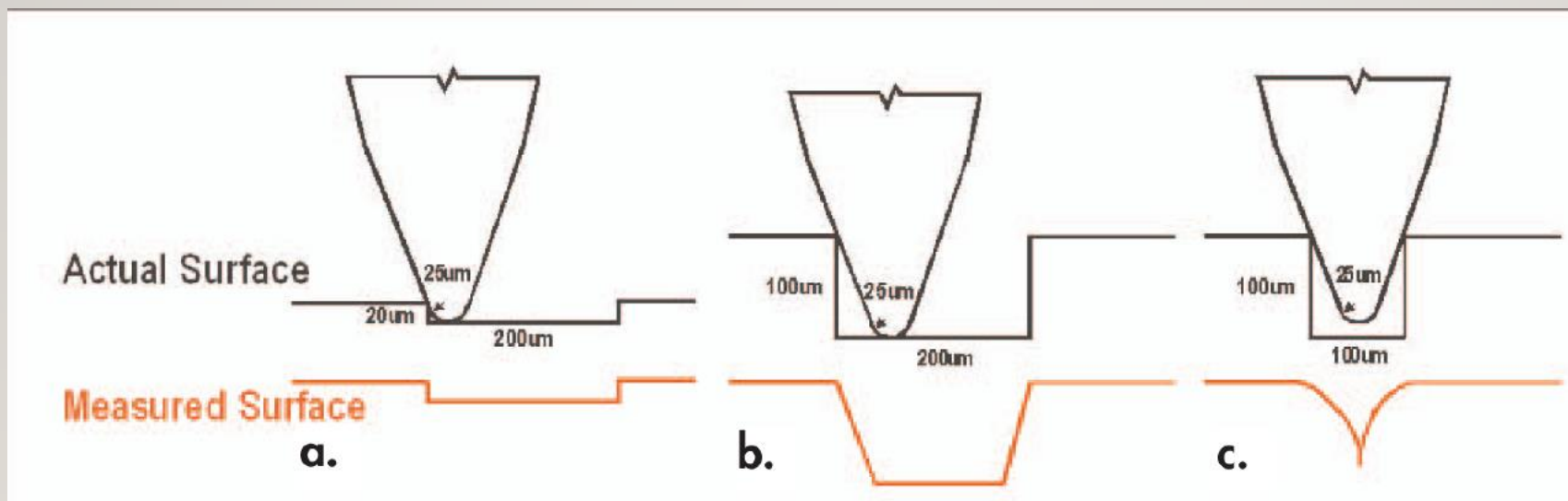
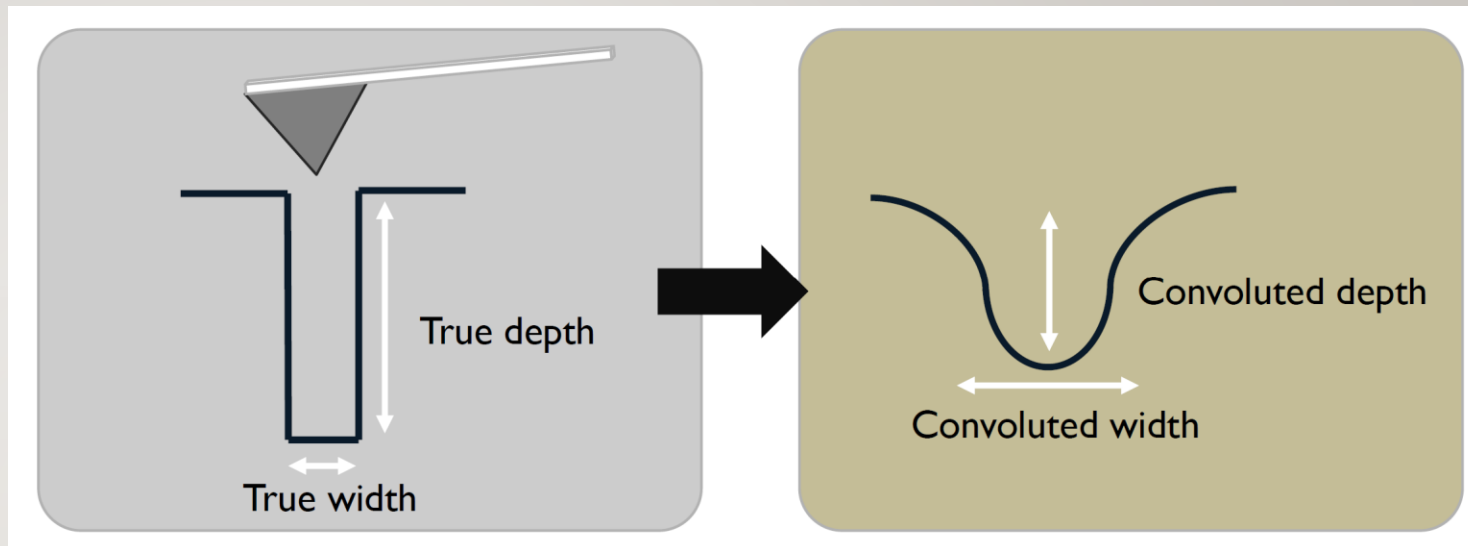


Very time consuming

Tip Radius and Convolution Effects

Radius of curvature of the tip defines the lateral resolution.

- Not only leads to convoluted x,y dimensions, can caused convoluted depth... effects surface roughness



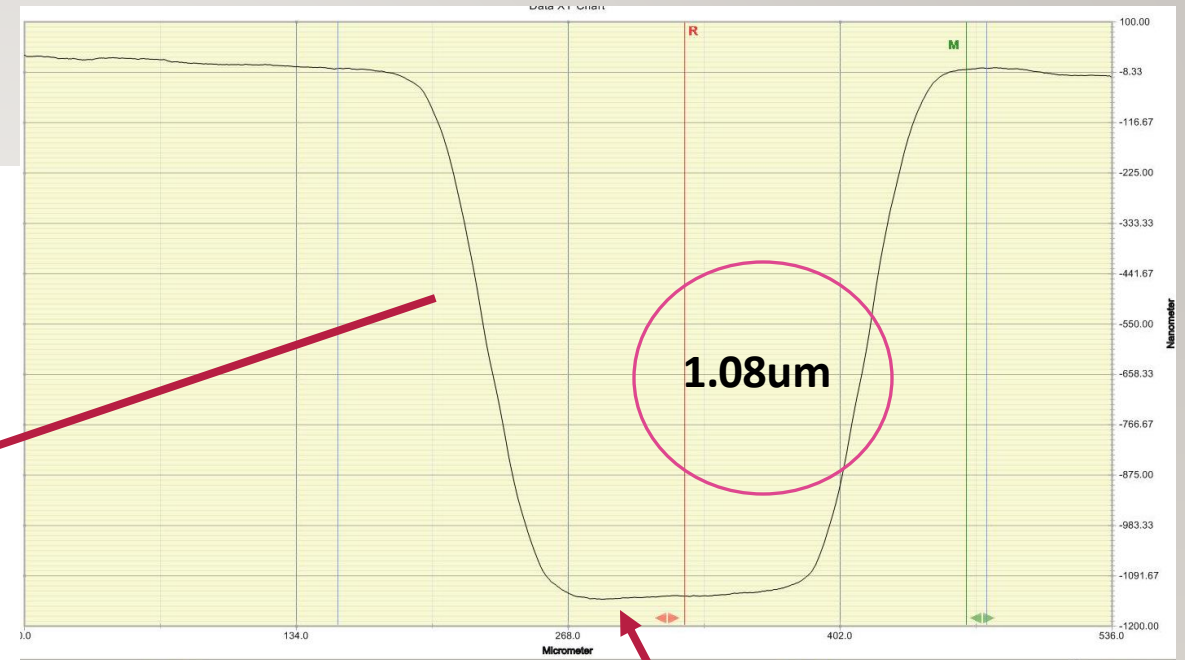
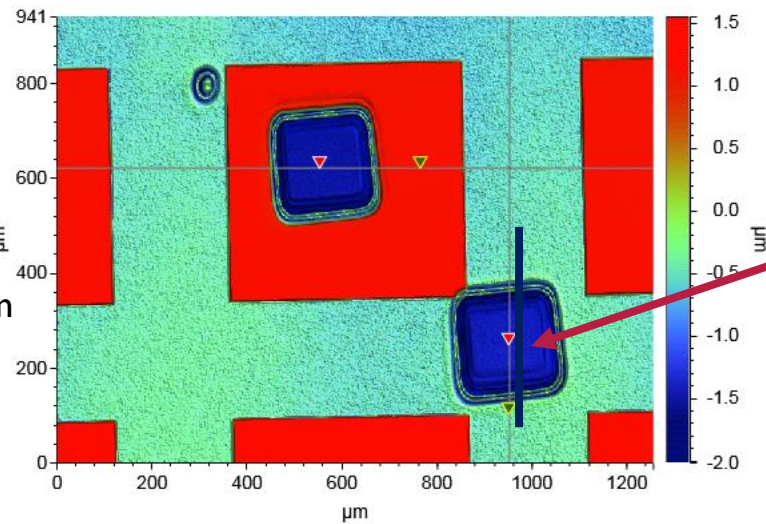
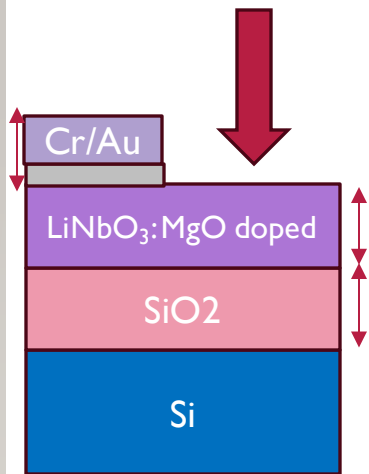
Features

- 3D topographical surface map rather than just traditional line scan
- Larger sample (up to 6 inches wafer) and longer scan (up to 55 mm)
- Vertical resolution - 1 ångström
- Vertical Range - 524 μm
- Powerful and user-friendly software
- Stylus radius- 12.5 μm , 5.0 μm , 2.5 μm

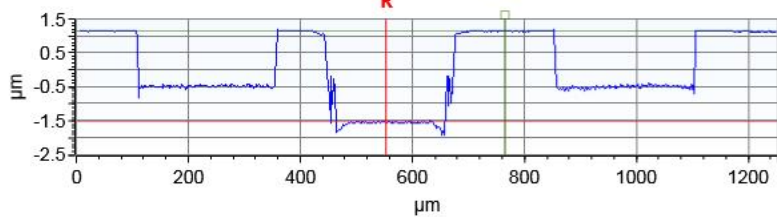
Data Information

- Step height
- Roughness
- Curvature measurement
- Film stress measurement

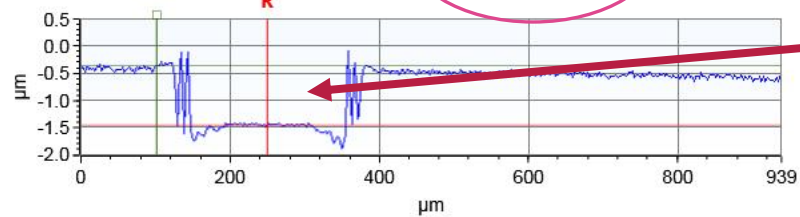
Data Collected from Optical and Stylus Profilometer



X Profile: $\Delta X=212.0805 \mu\text{m}$; $\Delta Z=2.6631 \mu\text{m}$



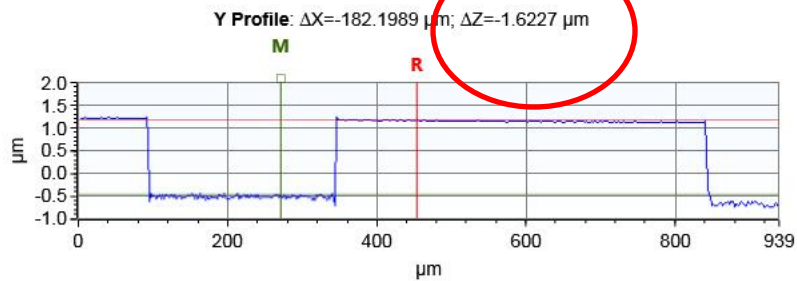
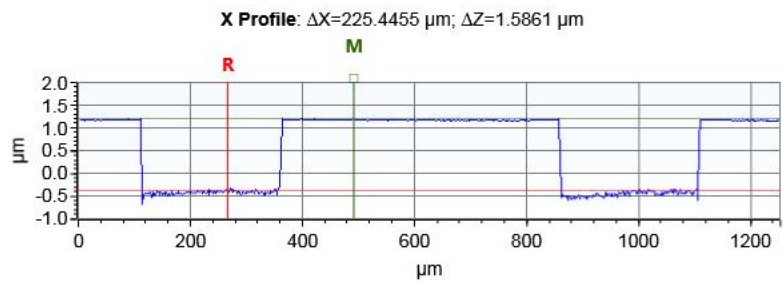
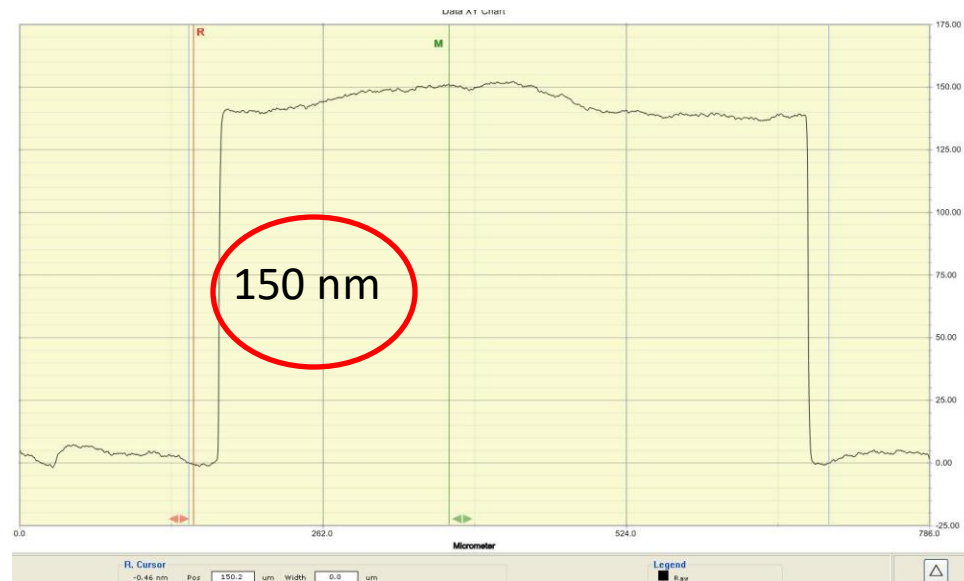
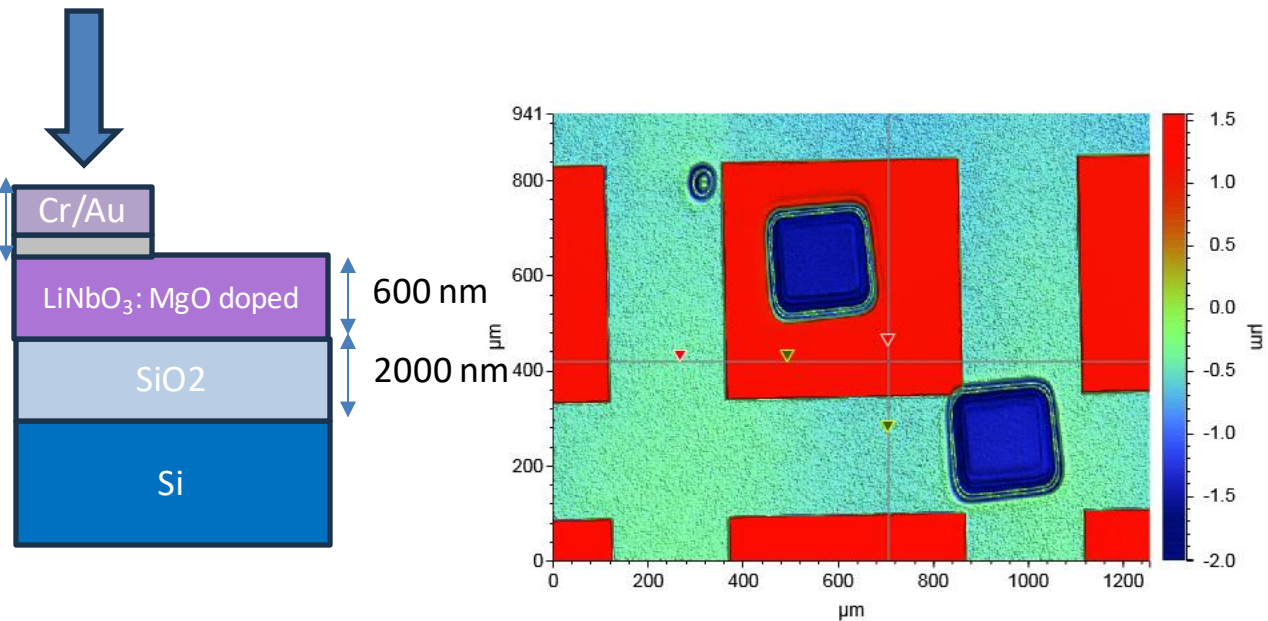
Y Profile: $\Delta X=-148.2599 \mu\text{m}$; $\Delta Z=1.0884 \mu\text{m}$



The depth of the crater

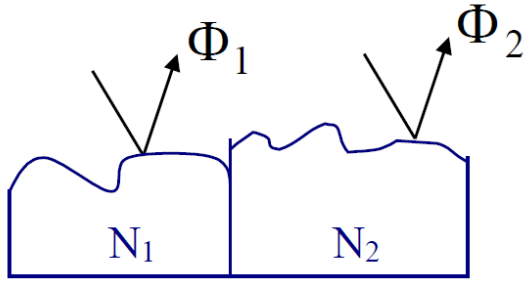
The results are very similar.

Error from Optical Profilometer



WHY?

Phase Change on Reflection



- Light, when reflected from materials, exhibits a phase change upon reflection
- Actual phase change is a function of the complex index of refraction: $N = n - ik$
- For a bulk material the phase change on reflection is given by:

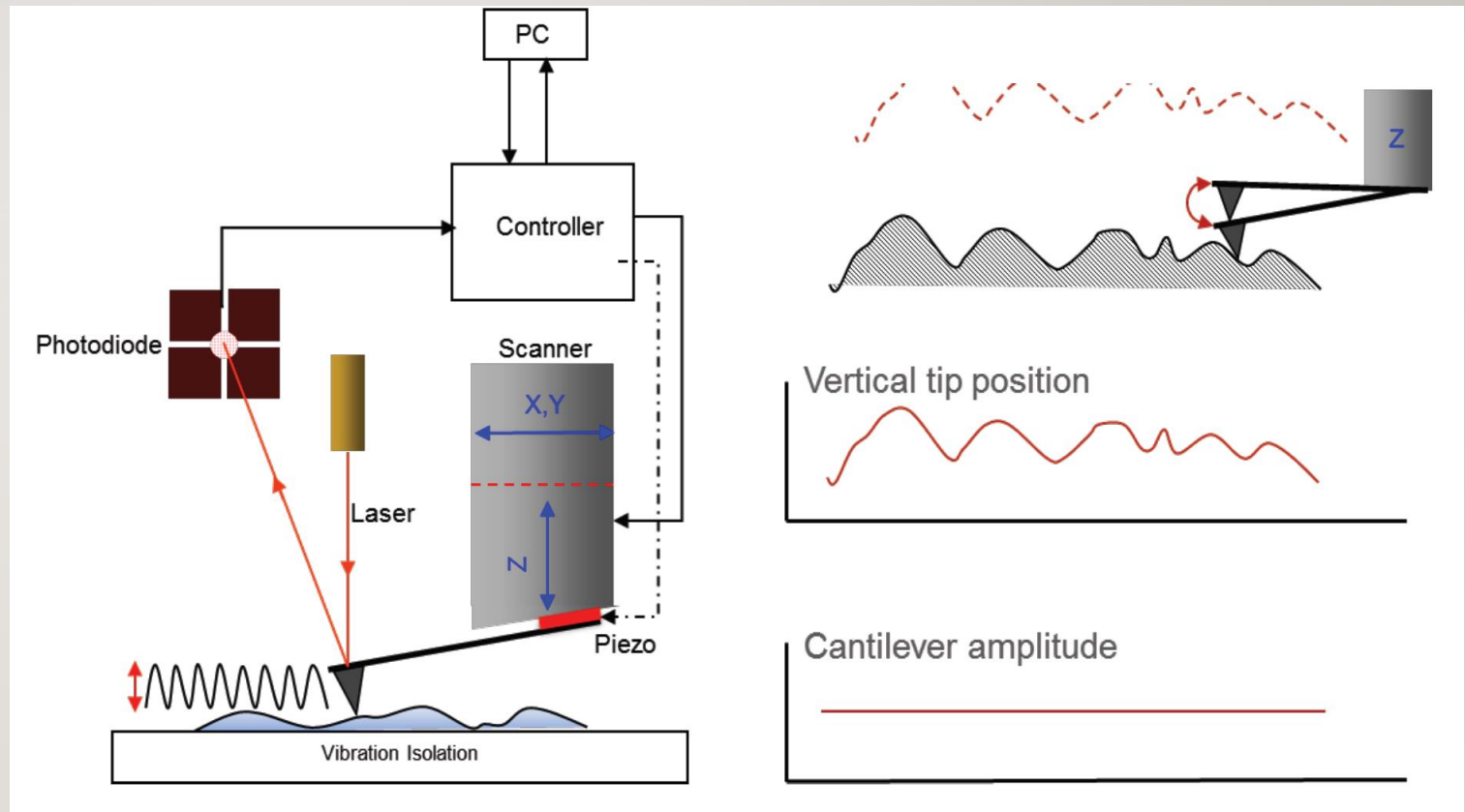
$$\Phi(n, k) = \text{TAN}^{-1} \left[\frac{2k}{1 - k^2 - n^2} \right]$$

Correction for the offset caused by the dissimilar materials

- Adjacent regions of dissimilar materials will have a constant offset due to difference in phase change on reflection
- The offset can be calculated once the n and k are known for both materials

$$\Delta h = \frac{\lambda}{4\pi} \Delta\Phi = \frac{\lambda}{4\pi} \left[\Phi(n_1, k_1) - \Phi(n_2, k_2) \right]$$

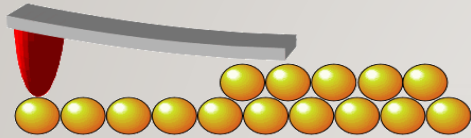
AFM (Atomic Force Microscopy) SPM (Scanning Probe Microscopy)



- Cantilever is driven at its resonant frequency by a piezo.
- The amplitude is monitored by laser deflection.
- Constant amplitude is maintained by adjusting the z piezo up or down.

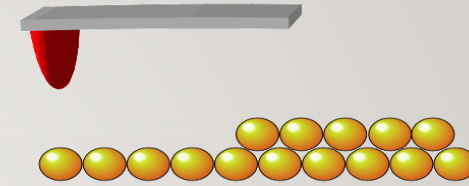
AFM Mode

contact mode



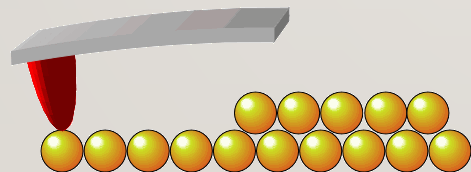
- Tip angstroms from surface (repelled)
- Constant force
- Highest resolution
- May damage surface

non-contact mode



- Tip hundreds of angstroms from surface (attracted)
- Variable force measured
- Lowest resolution
- Non-destructive

tapping mode

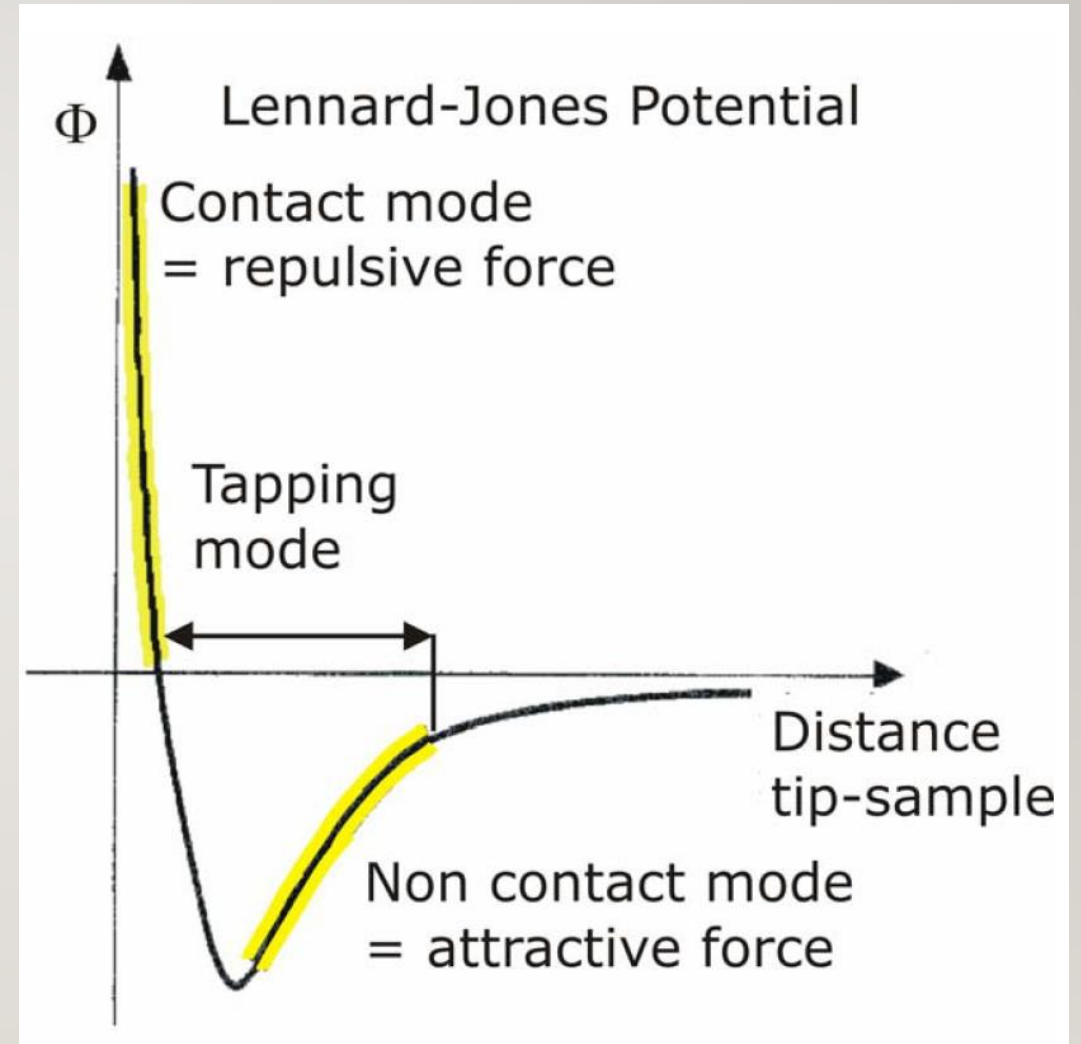


- Intermittent tip contact
- Variable force measured
- Improved resolution
- Non-destructive

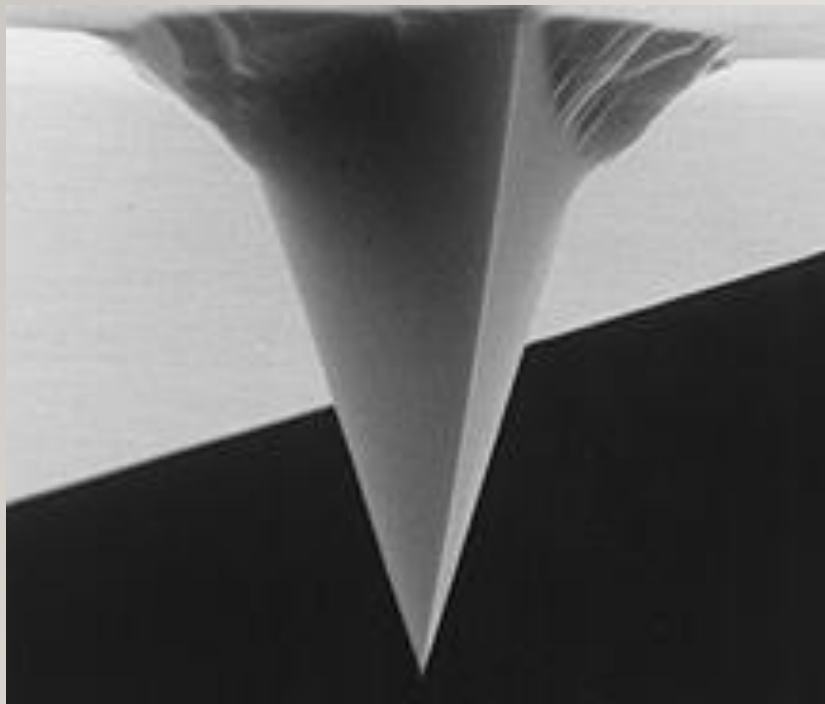
Tapping Mode

- A cantilever with attached tip is **oscillated at its resonant frequency** and scanned across the sample surface
- A constant oscillation amplitude (and thus a constant tip-sample interaction) are maintained during scanning. Typical amplitudes are 20-100 nm.
- Forces can be 200 pN or less
- The amplitude of the oscillations changes when the tip scans over bumps or depressions on a surface

The development of TappingMode™ enabled researchers to image samples too **fragile** to withstand the lateral forces of Contact Mode and use scan speeds much higher than could be obtained in non-contact mode.

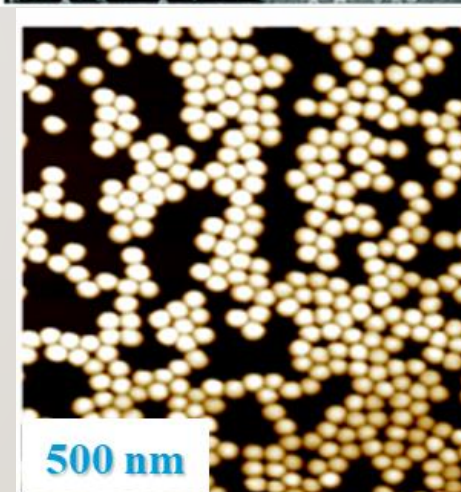
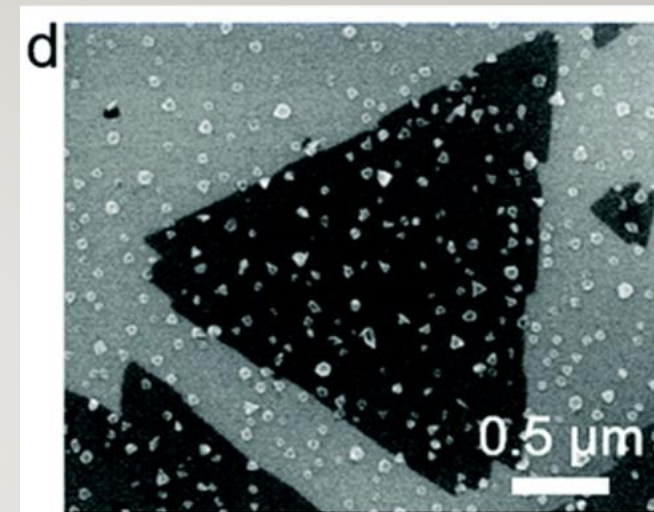
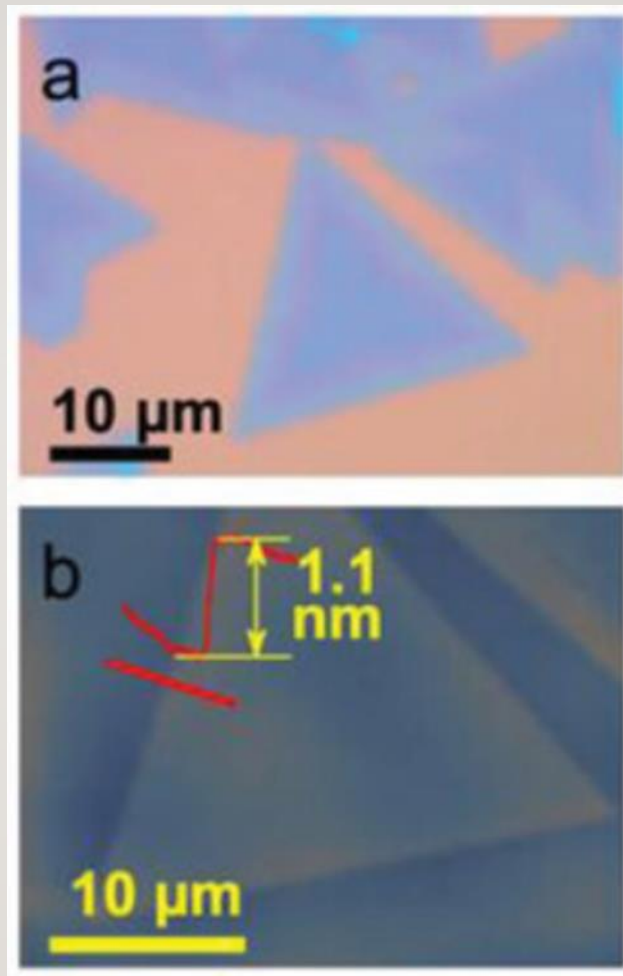


Microfabricated AFM cantilevers



Radius_{tip} ~ 1nm to 20nm

Only can be used for a few times

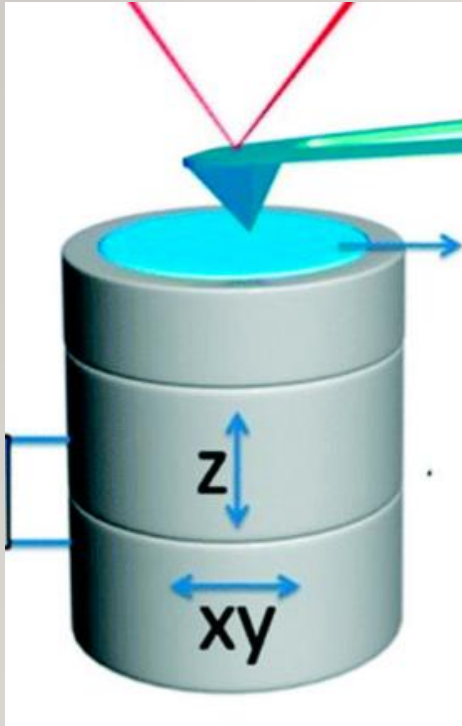


ZnS nanoparticles

P.Yasaei, et al "Spatial Mapping of Hot-Spots at Lateral Heterogeneities in Monolayer Transition Metal Dichalcogenides." *Advanced Materials* 1808244 (2019)

Y. Li et al, MoS₂-capped Cu_xS nanocrystals: a new heterostructured geometry of transition metal dichalcogenides for broadband optoelectronics. *Materials Horizons* 6 (3), 587-594. (2019)

Piezo stage used for AFM



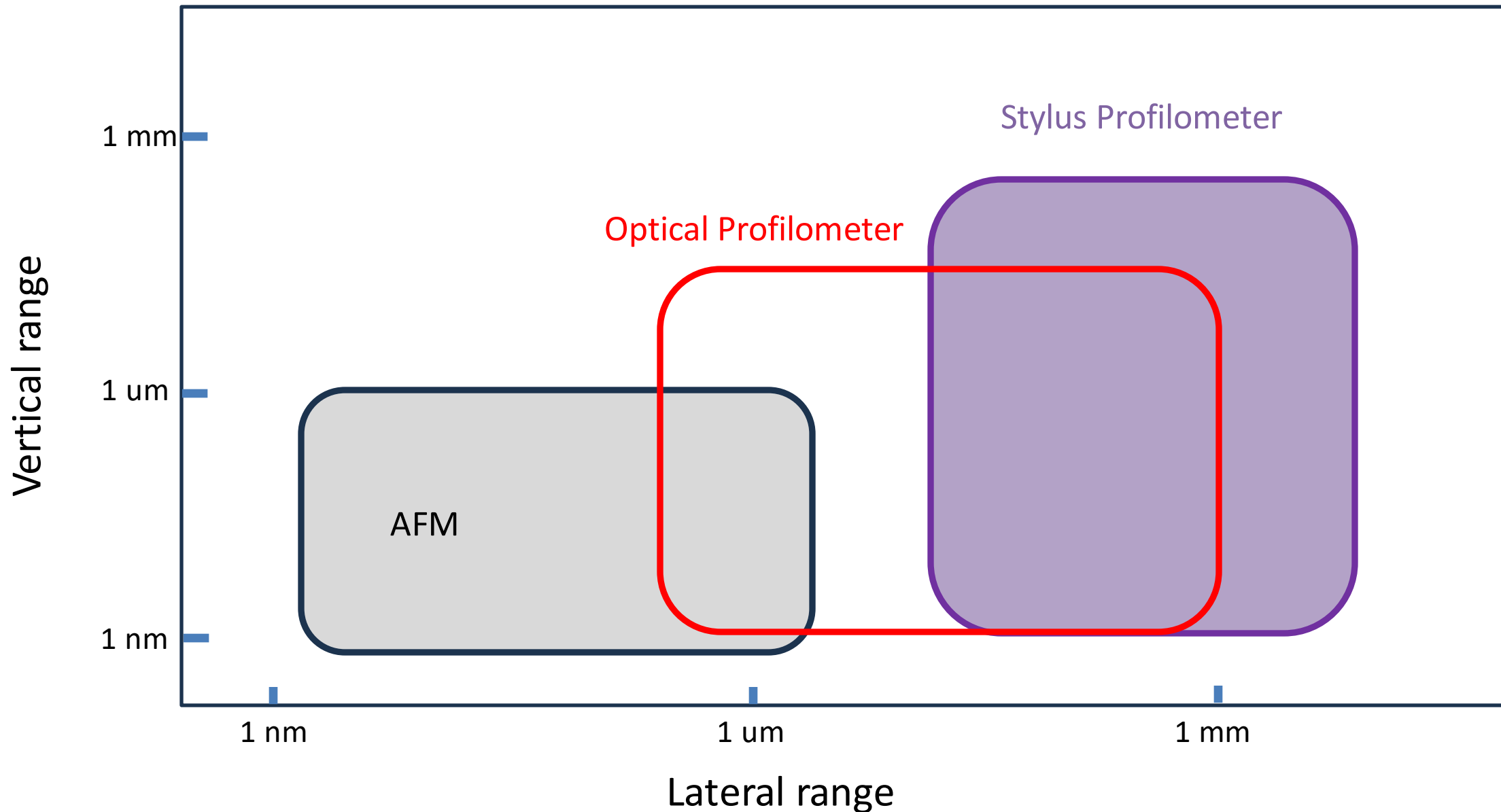
X and y translation precision
Smaller range

Motorized stage used for Profilometer



Huge x and y translation range
Poor precision

	Strength	Weakness
Stylus Surface Profiler (Contact profilometer)	<p>Very fast and very easy (no setup and focus time, don't need changing tip)</p> <p>Vertical data are always reliable (no artifact)</p> <p>Huge vertical range (524 um)</p> <p>Great vertical resolution</p>	<p>Poor lateral resolution</p> <p>Contact mode, damage the soft surface</p> <p>Time consuming for 3D characterization</p>
3D Optical Microscope (Optical profilometer)	<p>Fast and easy</p> <p>Quick 3D characterization</p> <p>No contact, good for soft surface</p> <p>Great vertical resolution</p> <p>Better lateral resolution</p>	<p>Not work for low reflective surface</p> <p>Artifact is possible for dissimilar surface</p>
Atomic Force Microscope (Tapping mode AFM)	<p>Best lateral and vertical resolution</p> <p>Great for atomic layer film</p> <p>Great for soft surface</p>	<p>X,Y,Z range is very limited</p> <p>The tip should be replaced very frequently</p> <p>Setup and scanning take more time</p>



THANKS FOR
YOUR
ATTENTION

- QUESTIONS?
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 - 847-491-5505
-